

54F/74F219 64-Bit Random Access Memory with TRI-STATE® Outputs

General Description

The 'F219 is a high-speed 64-bit RAM organized as a 16-word by 4-bit array. Address inputs are buffered to minimize loading and are fully decoded on-chip. The outputs are TRI-STATE and are in the high-impedance state whenever the Chip Select $(\overline{\text{CS}})$ input is HIGH. The outputs are active only in the Read mode. This device is similar to the 'F189 but features non-inverting, rather than inverting, data outputs.

Features

- TRI-STATE outputs for data bus applications
- Buffered inputs minimize loading
- Address decoding on-chip
- Diode clamped inputs minimize ringing
- Available in SOIC (300 mil only)

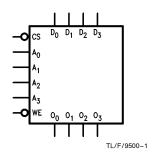
Commercial	Military	Package Number	Package Description		
74F219PC		N16E	16-Lead (0.300" Wide) Molded Dual-In-Line		
	54F219DL (Note 2)	J16A	16-Lead Ceramic Dual-In-Line		
74F219SC (Note 1)		M16B	16-Lead (0.300" Wide) Molded Small Outline, JEDEC		
74F219SJ (Note 1)		M16D	16-Lead (0.300" Wide) Molded Small Outline, EIAJ		
	54F219FL (Note 2)	W16A	16-Lead Cerpack		
	54F219LL (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C		

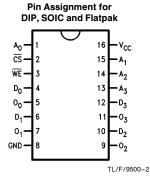
Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

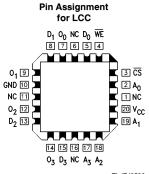
Note 2: Military grade device with environmental and burn-in processing. Use suffix = DLQB, FLQB and LLQB.

Logic Symbol

Connection Diagrams







TL/F/9500-3

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Unit Loading/Fan Out

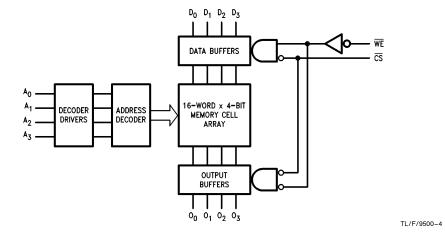
		54F/74F				
Pin Names	Description	U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}			
A ₀ -A ₃	Address Inputs	1.0/1.0	20 μA/-0.6 mA			
CS	Chip Select Input (Active LOW)	1.0/2.0	20 μA/ – 1.2 mA			
WE	Write Enable Input (Active LOW)	1.0/1.0	20 μA/ – 0.6 mA			
D ₀ -D ₃	Data Inputs	1.0/1.0	20 μA/-0.6 mA			
O ₀ -O ₃	TRI-STATE Data Outputs	150/40 (33.3)	−3 mA/24 mA (20 mA)			

Function Table

Inputs		Operation	Condition of Outputs				
CS	WE	operation	containen of outputs				
L	L	Write	High Impedance				
L	Н	Read	True Stored Data				
Н	X	Inhibit	High Impedance				

 $\begin{array}{l} H = \mbox{HIGH Voltage Level} \\ L = \mbox{LOW Voltage Level} \\ X = \mbox{Immaterial} \end{array}$

Block Diagram



Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{lll} \text{Storage Temperature} & -65^{\circ}\text{C to} + 150^{\circ}\text{C} \\ \text{Ambient Temperature under Bias} & -55^{\circ}\text{C to} + 125^{\circ}\text{C} \\ \text{Junction Temperature under Bias} & -55^{\circ}\text{C to} + 175^{\circ}\text{C} \\ \text{Plastic} & -55^{\circ}\text{C to} + 150^{\circ}\text{C} \\ \end{array}$

V_{CC} Pin Potential to

Ground Pin -0.5V to +7.0V Input Voltage (Note 2) -0.5V to +7.0V

Input Current (Note 2) $$-30\ \text{mA}$\ \text{to}$\ +5.0\ \text{mA}$$

Voltage Applied to Output

in HIGH State (with $V_{CC} = 0V$)

 Current Applied to Output in LOW State (Max)

twice the rated IOL (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature

Military -55°C to +100°C Commercial 0°C to +70°C

Supply Voltage

Military +4.5V to +5.5V Commercial +4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter		54F/74F			Units	Vcc	Conditions		
Symbol	raiaile		Min	Тур	Max	Onits	VCC	Conditions		
V _{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal		
V _{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal		
V _{CD}	Input Clamp Diode Vo	oltage			-1.2	V	Min	$I_{\text{IN}} = -18 \text{mA}$		
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 54F 10% V _{CC} 74F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC} 74F 5% V _{CC}	2.5 2.4 2.5 2.4 2.7 2.7			V	Min	$I_{OH} = -1 \text{ mA}$ $I_{OH} = -3 \text{ mA}$ $I_{OH} = -1 \text{ mA}$ $I_{OH} = -3 \text{ mA}$ $I_{OH} = -1 \text{ mA}$ $I_{OH} = -3 \text{ mA}$ $I_{OH} = -3 \text{ mA}$		
V _{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}			0.5 0.5	٧	Min	$I_{OL} = 20 \text{ mA}$ $I_{OL} = 24 \text{ mA}$		
I _{IH}	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	V _{IN} = 2.7V		
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V _{IN} = 7.0V		
I _{CEX}	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	$V_{OUT} = V_{CC}$		
V _{ID}	Input Leakage Test	74F	4.75			٧	0.0	$I_{\text{ID}} = 1.9 \mu\text{A}$ All Other Pins Grounded		
I _{OD}	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V _{IOD} = 150 mV All Other Pins Grounded		
I _{IL}	Input LOW Current				-0.6 -1.2	mA	Max	$\begin{aligned} V_{IN} &= 0.5 V \left(A_n, \overline{WE}, D_n \right) \\ V_{IN} &= 0.5 V \left(\overline{CS} \right) \end{aligned}$		
lozh	Output Leakage Curre	ent			50	μΑ	Max	V _{OUT} = 2.7V		
l _{OZL}	Output Leakage Current				-50	μΑ	Max	V _{OUT} = 0.5V		
los	Output Short-Circuit Current		-60		-150	mA	Max	V _{OUT} = 0V		
I _{ZZ}	Bus Drainage Test				500	μΑ	0.0V	V _{OUT} = 5.25V		
Icc	Power Supply Curren	t		37	55	mA	Max			

AC Electrical Characteristics

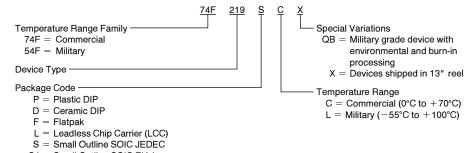
		$74F \\ T_{A} = +25^{\circ}C \\ V_{CC} = +5.0V \\ C_{L} = 50 pF$			$\begin{array}{c} 54F \\ T_A = +100^{\circ}C \\ V_{CC} = Mil \\ C_L = 50 \ pF \end{array}$		74F		Units
Symbol	Parameter						T _A , V _{CC} = Com C _L = 50 pF		
		Min	Тур	Max	Min	Max	Min	Max	
t _{PLH} t _{PHL}	Access Time, HIGH or LOW An to On	10.0 8.0	18.5 13.5	26.0 19.0	9.0 8.0	32.0 23.0	10.0 8.0	27.0 20.0	ns
t _{PZH}	Access Time, HIGH or LOW CS to On	3.5 5.0	6.0 9.0	8.5 13.0	3.5 5.0	10.5 15.0	3.5 5.0	9.5 14.0	ns
t _{PHZ}	Disable Time, HIGH or LOW CS to On	2.0 3.0	4.0 5.5	6.0 8.0	2.0 2.5	8.0 10.0	2.0 3.0	7.0 9.0	113
t _{PZH}	Write Recovery Time HIGH or LOW, WE to O _n	6.5 6.5	20.0 11.0	28.0 15.5	6.5 6.5	37.5 17.5	6.5 6.5	29.0 16.5	ns
t _{PHZ} t _{PLZ}	Disable Time, HIGH or LOW WE to On	4.0 5.0	7.0 9.0	10.0 13.0	3.5 5.0	12.0 15.0	4.0 5.0	11.0 14.0	113

AC Operating Requirements

		$74F$ $T_A = +25^{\circ}C$ $V_{CC} = +5.0V$		54	F	74F T _A , V _{CC} = Com		Units
Symbol	Parameter			T _A = +				
		Min	Max	Min	Max	Min	Max	
t _s (H) t _s (L)	Setup Time, HIGH or LOW A _n to WE	0 0		0		0 0		ns
t _h (H)	Hold Time, HIGH or LOW A _n to WE	2.0 2.0		2.0 2.0		2.0 2.0		113
t _S (H)	Setup Time, HIGH or LOW D _n to WE	10.0 10.0		11.0 11.0		10.0 10.0		ns
t _h (H) t _h (L)	Hold Time, HIGH or LOW D _n to WE	0		2.0 2.0		0		- 115
t _s (L)	Setup Time, LOW CS to WE	0		0		0		ns
t _h (L)	Hold Time, LOW CS to WE	6.0		7.5		6.0		115
t _w (L)	WE Pulse Width, LOW	6.0		15.0		6.0		ns

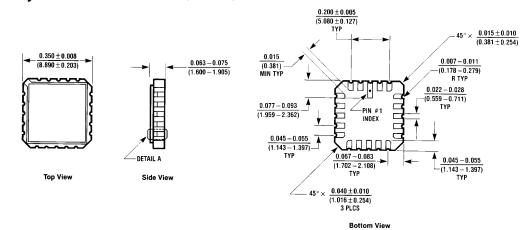


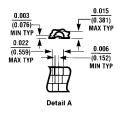
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



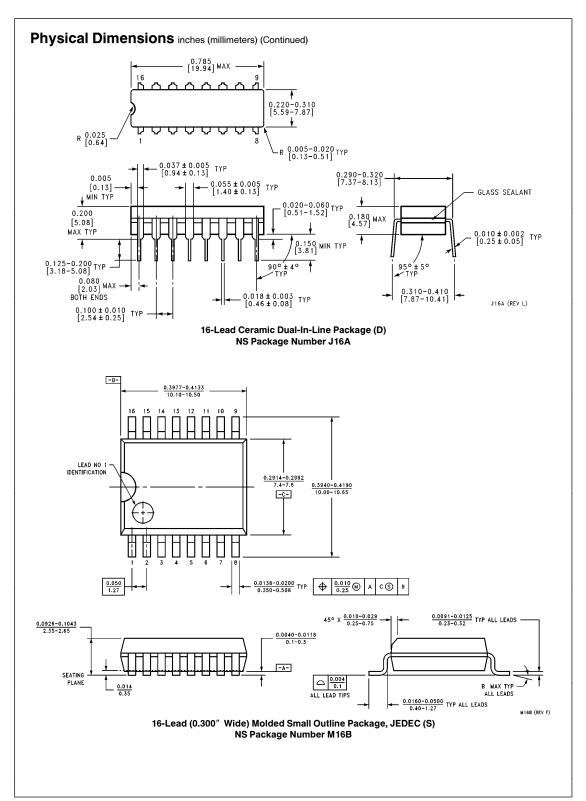
Physical Dimensions inches (millimeters)

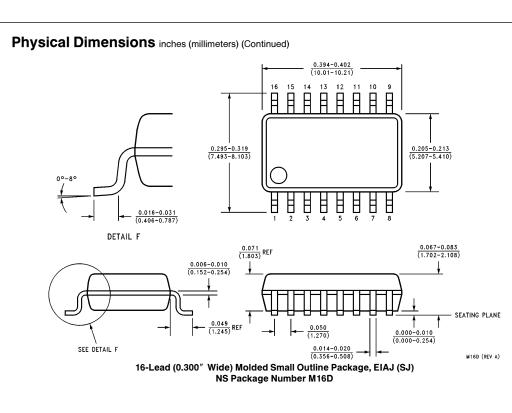
SJ = Small Outline SOIC EIAJ

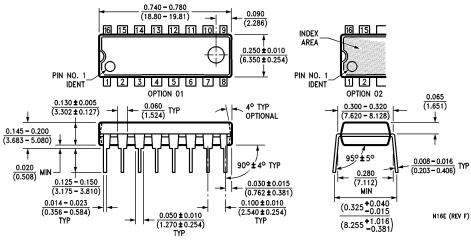




20-Lead Ceramic Leadless Chip Carrier (L) NS Package Number E20A E20A (REV D)

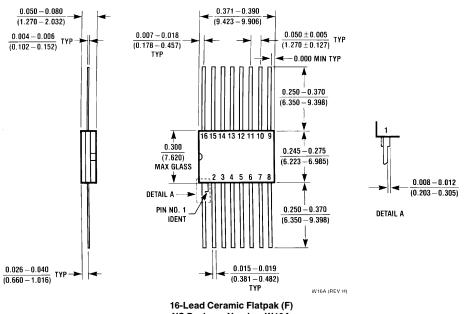






16-Lead (0.300" Wide) Molded Dual-In-Line Package (P)
NS Package Number N16E

Physical Dimensions inches (millimeters) (Continued)



NS Package Number W16A

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